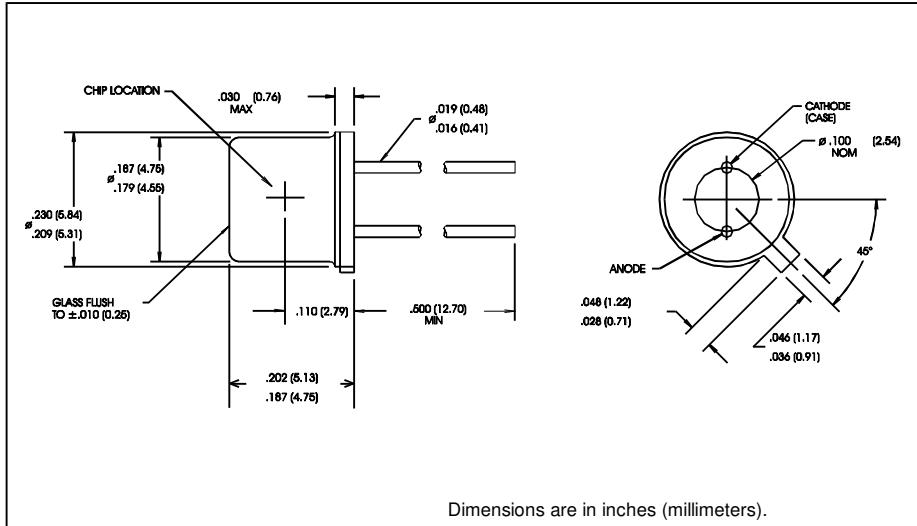


PIN Silicon Photodiode Type OP910W



Dimensions are in inches (millimeters).

Features

- Wide receiving angle
- Fast switching time
- Linear response vs. irradiance
- Enhanced temperature range

Description

The OP910W consists of a PIN silicon photodiode mounted in a two-leaded hermetic TO-46 package. The flat lens has an acceptance half angle of $\pm 40^\circ$.

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

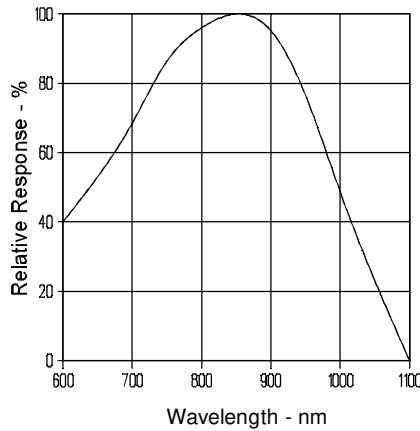
| | |
|---|---|
| Reverse Voltage | 60 V |
| Storage Temperature Range | -65 $^\circ\text{C}$ to +150 $^\circ\text{C}$ |
| Operating Temperature Range | -65 $^\circ\text{C}$ to +125 $^\circ\text{C}$ |
| Lead Soldering Temperature [1/16 inch (1.6mm) from case for 5 sec. with soldering iron] | 200 $^\circ\text{C}$ ⁽¹⁾ |
| Power Dissipation | 250 mW |

Notes:

- (1) RMA Flux is recommended. Duration can be extended to 10 sec. max. when flow soldering.
- (2) Light source is an unfiltered GaAs LED with a peak wavelength of 935 nm and a radiometric intensity level which varies less than 10% over the entire lens surface of the photodiode being tested.
- (3) Junction temperature maintained at 25 $^\circ\text{C}$.
- (4) To calculate typical dark current in nA, use the formula $I_D=10^{(0.42 T_A - 1.5)}$ where T_A is ambient temperature in $^\circ\text{C}$.
- (5) Derate linearly 2.5 mW/ $^\circ\text{C}$ above 25 $^\circ\text{C}$.

Typical Performance Curves

Typical Spectral Response

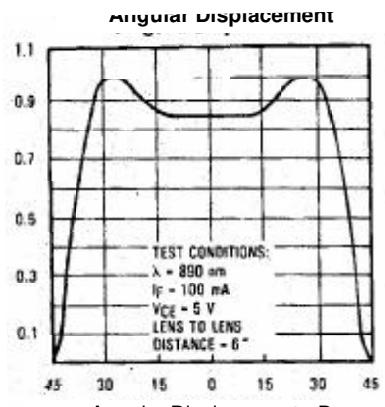
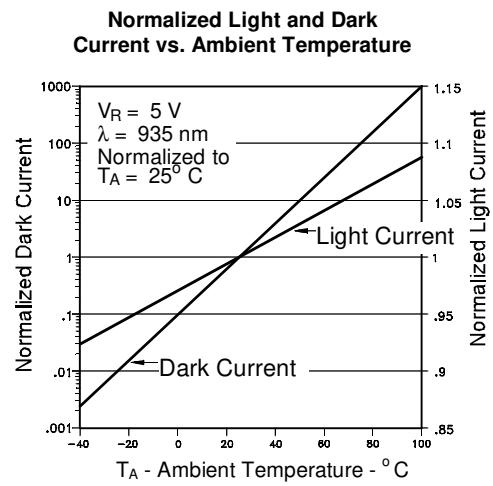
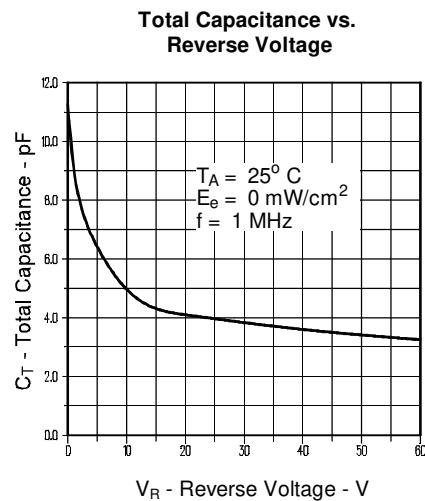
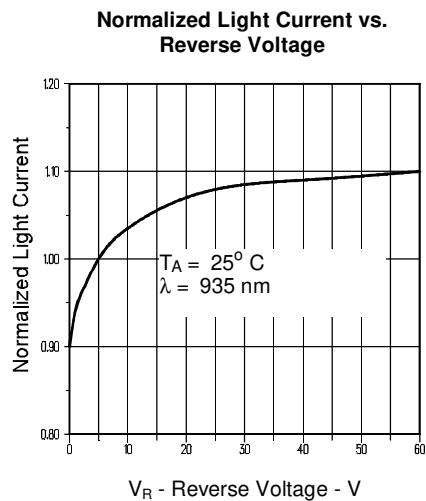


Type OP910W

Electrical Characteristics ($T_A = 25^\circ C$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITION |
|-------------|---------------------------|-----|-------|-----|-------|--|
| I_L | Light Current | 1.7 | 2.4 | | mA | $V_R = 20 V$, $E_e = .50 \text{ mW/cm}^2$ note 2, 3 |
| I_D | Dark Current | | 1 | 10 | nA | $V_R = 20 V$, $E_e = 0.0$ |
| $V_{(BR)R}$ | Reverse Voltage Breakdown | 100 | | | V | $I_R = 100 \text{ mA}$ |
| t_r | Rise Time | | 10 | | nS | $V_R = 20 V$, $R_L = 50 \text{ OHMS}$ |
| t_f | Fall Time | | 10 | | nS | $V_R = 20 V$, $R_L = 50 \text{ OHMS}$ |
| \emptyset | Half Angle | | +/-40 | | degr. | $I_F = \text{Constant}$ |
| C_P | Capacitance | | 13 | | pF | $V_R = 0 V$, $F = 1 \text{ MHz}$, $E_e = 0$ |
| V_F | Forward Voltage | | | 1.2 | V | $I_F = 100 \text{ mA}$ |

Typical Performance Curves



Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.

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